

Distortion-induced effects in nematic liquid crystals

Ferroelectric phenomena in liquid crystals
Kent State University

June 19 - 28, 2007

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Outline

- Introduction to nematic liquid crystals

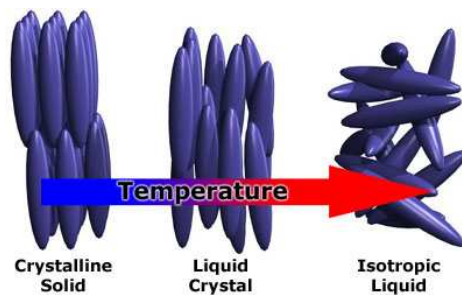
- Effective weak anchoring

- Statement of the problem
- Surface melting
- Effective surface tilt angle
- Effective weak anchoring

- Induced biaxiality

- Statement of the problem
- Elastic energy
- Examples

Nematic liquid crystals



- Orientational probability distribution

$$f_p : \mathbb{S}^2 \rightarrow \mathbb{R}_+$$

- Tensor order parameter:

$$\mathbf{Q} = \langle \mathbf{m} \otimes \mathbf{m} - \frac{1}{3} \mathbf{I} \rangle = s \left(\mathbf{n} \otimes \mathbf{n} - \frac{1}{3} \mathbf{I} \right) + \beta \left(\mathbf{e}_+ \otimes \mathbf{e}_+ - \mathbf{e}_- \otimes \mathbf{e}_- \right)$$

- $s \in [-\frac{1}{2}, 1]$ is the **degree of orientation**, \mathbf{n} is the **director** (local preferred orientation if $s > 0$), β measures the degree of **biaxiality**
- The phase can be isotropic ($s = \beta = 0$), uniaxial ($s \neq 0, \beta = 0$) or biaxial ($s \neq 0, \beta \neq 0$)

Free energy functional

- Free energy density: $\Psi = \frac{K}{2} |\nabla \mathbf{Q}|^2 + A \text{tr} \mathbf{Q}^2 - B \text{tr} \mathbf{Q}^3 + C \text{tr} \mathbf{Q}^4$
- Ψ is the sum of the elastic term and the Landau-de Gennes potential
- Elastic term penalizes distortions, Landau-de Gennes potential is minimized when \mathbf{Q} is **uniaxial** with fixed degree of orientation
- In the uniaxial case ($\beta = 0$)

$$|\nabla \mathbf{Q}|^2 = \frac{2}{3} |\nabla s|^2 + 2s^2 |\nabla \mathbf{n}|^2$$

$$\Psi_{LdG}(s) = \frac{2}{9} C s^4 - \frac{2}{9} B s^3 + \frac{2}{3} A s^2$$

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- Anchoring = boundary conditions**
 - Strong, free anchoring \leftrightarrow Dirichlet, Neumann b.c.
 - Weak anchoring \leftrightarrow surface potential favouring a direction**

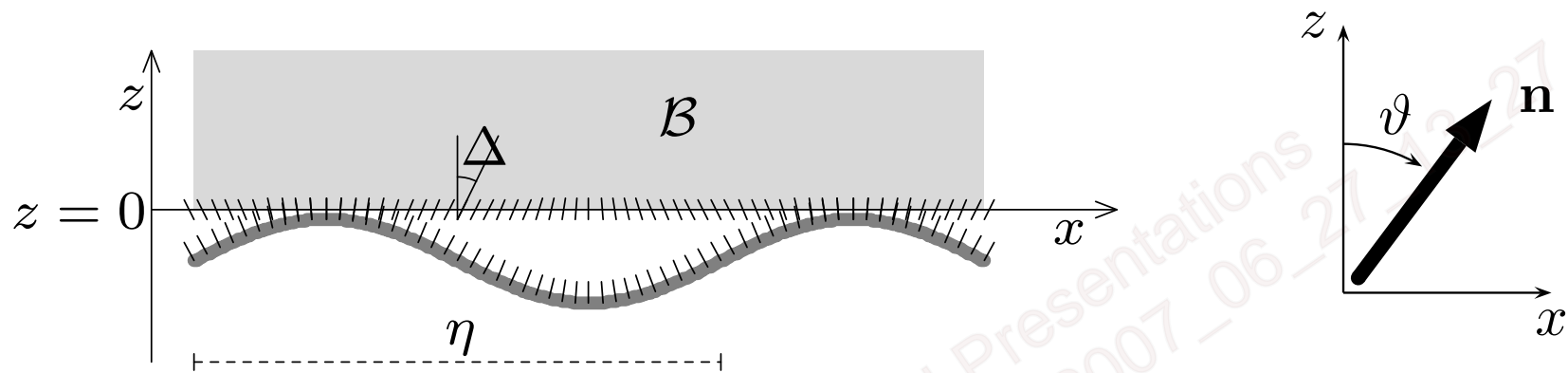
Effective weak anchoring

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Statement of the problem

- Anchoring potential can be viewed as the result of molecular interactions
- Anchoring is commonly imposed by rubbing \Rightarrow the geometry of the problem affects the anchoring potential!
- Another effect: decrease of s close to a rough-surface
- This decrease affects the director distribution (coupling given by $s^2 |\nabla \mathbf{n}|^2$)
- Our aim is to investigate the roughness influence on anchoring potential. A singular perturbation approach, new to the problem, is used

Modeling a rough boundary



We assume first a single wavelength.

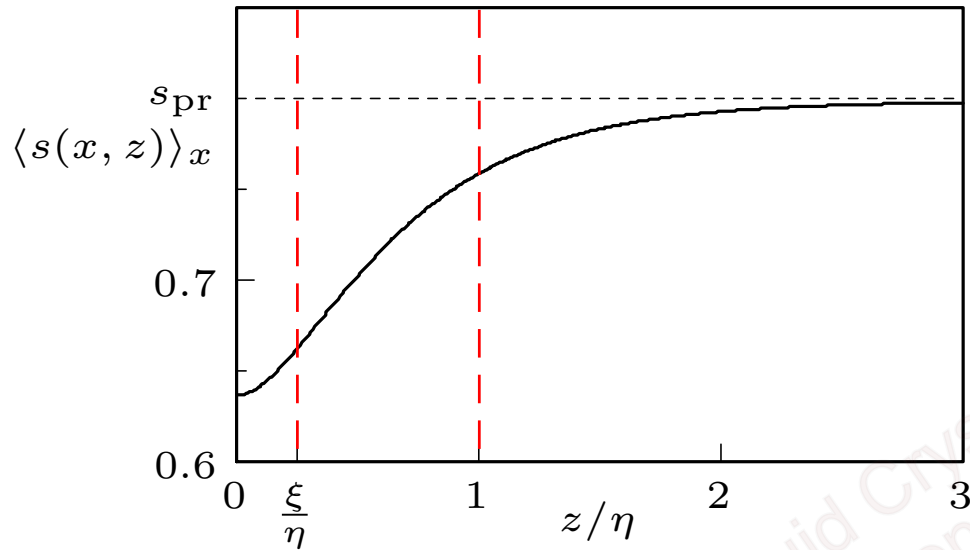
We expand in the roughness amplitude Δ .

At first order we obtain a sinusoidal modulation of ϑ along the x axis.

This modulation has wavelength η and amplitude linearly dependent on Δ .

The amplitude Δ and the wavelength η characterizing the grooves will be crucial parameters in our results.

Surface melting (Neumann)



Rough surface

$$\langle s(x, 0) \rangle_x \approx s_{pr} \left(1 - \frac{m^2 \xi^2}{\omega^2} - \frac{\Delta^2 \xi^2}{\omega^2 \eta^2} \right)$$

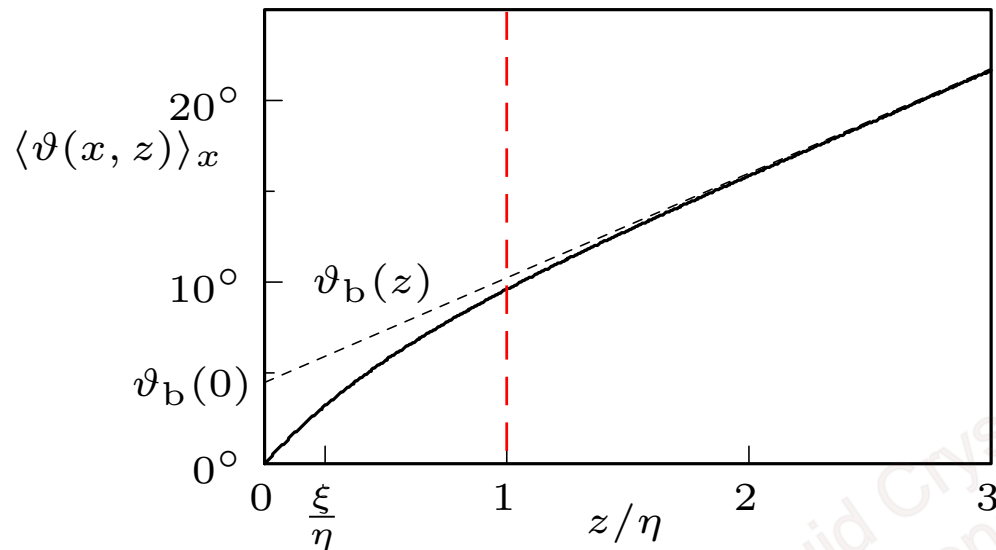
m is the slope of the *outer* solution at the boundary

$\xi = \sqrt{9K/C}$ is the **nematic coherence length**

ω^2 measures the potential depth of $f_{LdG}(s_{pr})$: $f''_{LdG}(s_{pr}) = K\omega^2/\xi^2$.

- **Two scale analysis**: *two* boundary layers, of thickness ξ , η . Physical situation: $\xi \ll \eta$
- **Outer solution**: uniform decrease of s triggered by m

Effective surface angle (Neumann)



Rough surface

$$\vartheta_b(0) \approx \frac{2 m \xi^2 \Delta^2}{\eta \omega^2}$$

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A coarse observation of the nematic configuration measures a surface **tilt angle slightly different from the homeotropic prescription** $\vartheta_{\text{surf}} = 0$.

Effective weak anchoring

We want to compare our results with a classical weak-anchoring model

- A tilt angle $\vartheta_b(0) \neq 0$ may also be modeled through a weak anchoring potential $W f_w$, where W is the anchoring strength
- Define the surface extrapolation length $\zeta = \frac{K}{W f_w''(0)}$
- Comparison with our result relates ζ to the microscopic roughness parameters

- s free at the surface $\Rightarrow \frac{\zeta}{\xi} = \frac{2\Delta^2}{\omega^2} \frac{\xi}{\eta} + \mathcal{O}\left(\frac{\xi^2}{\eta^2}\right)$

Anchoring strength increases when either the roughness amplitude Δ decreases or the roughness wavelength η increases

Conclusions - Part I

- The roughness induces a partial melting (decrease of s) close to the surface in a layer of thickness η
- This decrease favours a steep shape of ϑ
- Comparison with effective weak anchoring allows to relate the anchoring potential with surface parameters

Induced biaxiality

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Predicting Biaxiality (I)

- Within de Gennes' theory, nematics have three different phases: isotropic, uniaxial and biaxial
- The free energy favors a uniaxial ground state, but **biaxial domains have been predicted and observed**
- It is well known that **defects** are often a **source of biaxiality!**
- Early theory, employing only the director \mathbf{n} as order parameter, cannot take biaxiality into account
- When this is a good approximation?

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- When this is a good approximation?

Can we predict where the biaxiality is most likely to arise (if any), once we know the director distribution?

Elastic free energy

$$\frac{K}{2} |\nabla \mathbf{Q}|^2 = K \left[\frac{1}{3} |\nabla s|^2 + |\nabla \beta|^2 + s^2 |\nabla \mathbf{n}|^2 + \beta^2 \left(|\nabla \mathbf{n}|^2 + 4 |(\nabla \mathbf{e}_+)^T \mathbf{e}_-|^2 \right) - 2s\beta \left(\mathbf{e}_+ \cdot \mathbf{S} \mathbf{e}_+ - \mathbf{e}_- \cdot \mathbf{S} \mathbf{e}_- \right) \right], \text{ where } \mathbf{S} = (\nabla \mathbf{n}) (\nabla \mathbf{n})^T$$

- \mathbf{S} is symmetric and \mathbf{n} is an eigenvector (with null eigenvalue)

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- \mathbf{S} is symmetric and \mathbf{n} is an eigenvector (with null eigenvalue)
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- Third term decreases s whenever $|\nabla \mathbf{n}| \neq 0$, [studied before!](#)

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- \mathbf{S} is symmetric and \mathbf{n} is an eigenvector (with null eigenvalue)
- First two terms penalize spatial variations
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- Last term is what shifts biaxiality away from $\beta = 0$

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- \mathbf{S} is symmetric and \mathbf{n} is an eigenvector (with null eigenvalue)
- First two terms penalize spatial variations
- Third term decreases s whenever $|\nabla \mathbf{n}| \neq 0$, *studied before!*
- Fourth term is positive definite \Rightarrow pushes the solution toward $\beta = 0$
- Last term is what shifts biaxiality away from $\beta = 0$
- It is minimum when $\{\mathbf{e}_+, \mathbf{e}_-\}$ coincide with the two eigenvectors of \mathbf{S} that are orthogonal to \mathbf{n}

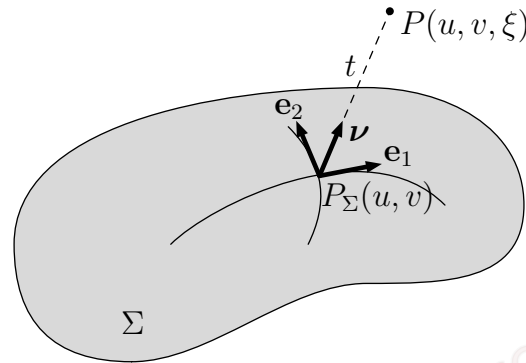
Predicting biaxiality (II)

Consider the symmetric tensor $\mathbf{S} = (\nabla \mathbf{n})(\nabla \mathbf{n})^T$. It always possesses a null eigenvalue (with eigenvector \mathbf{n}). Whenever its other two eigenvalues do not coincide, biaxiality is naturally induced in the system, and the optimal eigendirections of \mathbf{Q} coincide with those of \mathbf{S} .

Planar fields

- Planar fields \Rightarrow
$$\mathbf{n} = \cos \theta \mathbf{e}_x + \sin \theta \mathbf{e}_y$$
$$\mathbf{n}_\perp = -\sin \theta \mathbf{e}_x + \cos \theta \mathbf{e}_y$$
- $\nabla \mathbf{n} = \mathbf{n}_\perp \otimes \nabla \theta \Rightarrow \mathbf{S} = |\nabla \theta|^2 \mathbf{n}_\perp \otimes \mathbf{n}_\perp$
- There is spontaneous biaxiality whenever the tilt angle is not uniform

Surface biaxiality



Suppose that a liquid crystal is limited by a surface and homeotropic boundary conditions $\mathbf{n} \equiv \boldsymbol{\nu}$ are assumed.

$$\mathbf{S} = \frac{\kappa_1^2}{(1 - \kappa_1 t)^2} \mathbf{e}_1 \otimes \mathbf{e}_1 + \frac{\kappa_2^2}{(1 - \kappa_2 t)^2} \mathbf{e}_2 \otimes \mathbf{e}_2$$

κ_1, κ_2 are the principal curvatures
 $\mathbf{e}_1, \mathbf{e}_2$ are the principal axis

- Biaxiality arises along the principal axis
- The effect is triggered by the **difference between the principal curvatures**
- The preferred direction is the one with higher positive curvature

Escape in the third dimension

- Cylinder of radius R with homeotropic boundary conditions (Cladis and Kléman ^a)
- $\mathbf{n} = \cos \phi(r) \mathbf{e}_r + \sin \phi(r) \mathbf{e}_z$
 $\mathbf{n}_\perp = -\sin \phi(r) \mathbf{e}_r + \cos \phi(r) \mathbf{e}_z$
- $\mathbf{S} = \frac{\cos^2 \phi}{r^2} \mathbf{e}_\theta \otimes \mathbf{e}_\theta + \phi'^2 \mathbf{n}_\perp \otimes \mathbf{n}_\perp$
- Cladis and Kléman solution is $\phi(r) = \frac{\pi}{2} - 2 \arctan \frac{r}{R} \Rightarrow$
 $\phi'^2 = \cos^2 \phi / r^2$
- The escape in the third dimension is one example of spatially varying fields which **do not induce any biaxiality**

^aP. Cladis and M. Kléman, J. Physique **33**, 591 (1972).

Conclusions - Part II

- We have given an easy way to determine the “natural” directions of biaxiality
- Those are given by the eigenvectors of $\mathbf{S} = (\nabla \mathbf{n})(\nabla \mathbf{n})^T$
- Examples show for instance that surface biaxiality in the homeotropic case is ruled by the difference between the principal curvatures of the surface

References

- [1] P. Biscari, S. Turzi, *Boundary-roughness effects in nematic liquid crystals*, SIAM J. Appl. Math., **67** (2007), 447-463
- [2] P. Biscari, G. Napoli, S. Turzi *Bulk and surface biaxiality in nematic liquid crystals*, Phys. Rev E **74** (2006), 031708

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